

Customer Code : \_\_\_\_\_

# DATASHEET

DAPU P/N: DP7W12500012

\_\_\_\_\_

| Plot             |         |          | The Label              |
|------------------|---------|----------|------------------------|
| Drew             | Audited | Approved | Stamp, please! Thanks! |
|                  |         |          |                        |
| Date: 2019.01.25 |         |          |                        |

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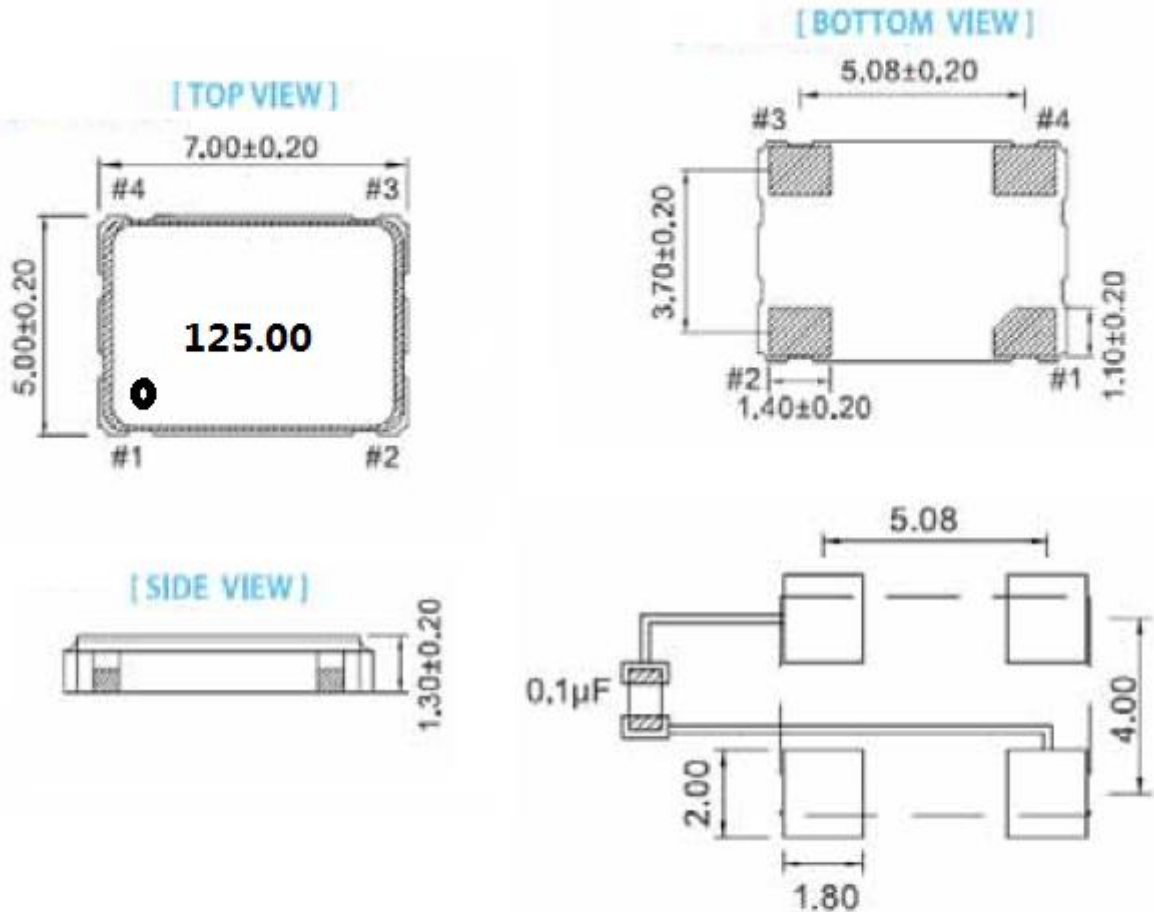


## 1、Electrical Parameters

| MODEL: DP7W12500012 |                               |                                |                  |      |   |                  |   |
|---------------------|-------------------------------|--------------------------------|------------------|------|---|------------------|---|
| No                  | Parameters                    | SYM.                           | Electrical Spec. |      |   |                  | Notes   |
|                     |                               |                                | Min.             | Typ. | Max.  | Units            |   |
| 1                   | Nominal Frequency             | FL                             | 125.00           |      |   | MHz              |   |
| 2                   | Output Waveform               |                                | CMOS             |      |   |                  |   |
| 3                   | Supply Voltage                |                                | 2.97             | 3.3  | 3.63  | V                |   |
| 4                   | Frequency Stability (Overall) | F-stab                         | -30              |      | +30   | $\times 10^{-6}$ | Frequency stability includes frequency tolerance@25 °C and frequency stability vs. operating temperature range and voltage variance and first year aging. |
| 5                   | Operating Temperature         | T-opr                          | -40              | ~    | +85   | °C               | The operating temperature range over which the frequency stability is measured.   |
| 6                   | Storage Temperature           | T-stg                          | -55              | ~    | +125  | °C               |   |
| 7                   | Current                       |                                | -                |      | 35  | mA               | At maximum supply voltage   |
| 8                   | Rise/Fall Time                | Tr、 Tf                         |                  |      | 3   | ns               |   |
| 9                   | Output Load                   |                                |                  |      | 15  | pF               |   |
| 10                  | Aging                         |                                | -3               |      | +3  | $\times 10^{-6}$ | Frequency drift in first year   |
| 11                  | Duty Cycle                    | DC                             | 45               | 50   | 55  | %                |   |
| 12                  | Output Voltage High           | VOH                            | 2.97             | -    | -   | V                |   |
| 13                  | Output Voltage Low            | VOL                            | -                | -    | 0.33  | V                |   |
| 14                  | Tri-State                     | Output Active                  | 2.31 or Floating | -    | -   | V                | Pin 1 Tri-state   |
|                     |                               | Output in High-Impedance state | -                | -    | 0.99  | V                |   |
| 15                  | Start Time                    | T_start                        | -                | -    | 8.0   | ms               |   |
| 16                  | Vibration Test                | MIL-STD-883 2007 Condition A   |                  |      | 10~2000Hz, 1.52mm, 20g, each axis for 4 hrs               |                  |   |
|                     |                               | JESD22-B103 Condition 1        |                  |      |   |                  |   |
| 17                  | Thermal Shock                 | MIL-STD-883 1010 Condition B   |                  |      | -55°C, 125°C; soak time is 10 mins, with total 200 cycles |                  |   |
|                     |                               | JESD22-A104 Condition B        |                  |      |   |                  |   |
| 18                  | Mechanical Shock              | MIL-STD-883 2002 Condition B   |                  |      | 1500g, half-sine, 0.5ms, each axis for 3 times.           |                  |   |
|                     |                               | JESD22-B104 Condition B        |                  |      |   |                  |   |



## 2、Mechanical Structure(mm)



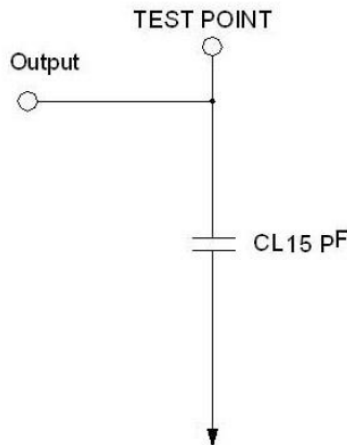
To ensure optimal oscillator performance, place a by-pass capacitor of  $0.1 \mu\text{F}$  as close to the part as possible between  $V_{DD}$  and GND pads.

| Pin | Function  |
|-----|-----------|
| #1  | Tri-State |
| #2  | GND       |
| #3  | Output    |
| #4  | $V_{DD}$  |

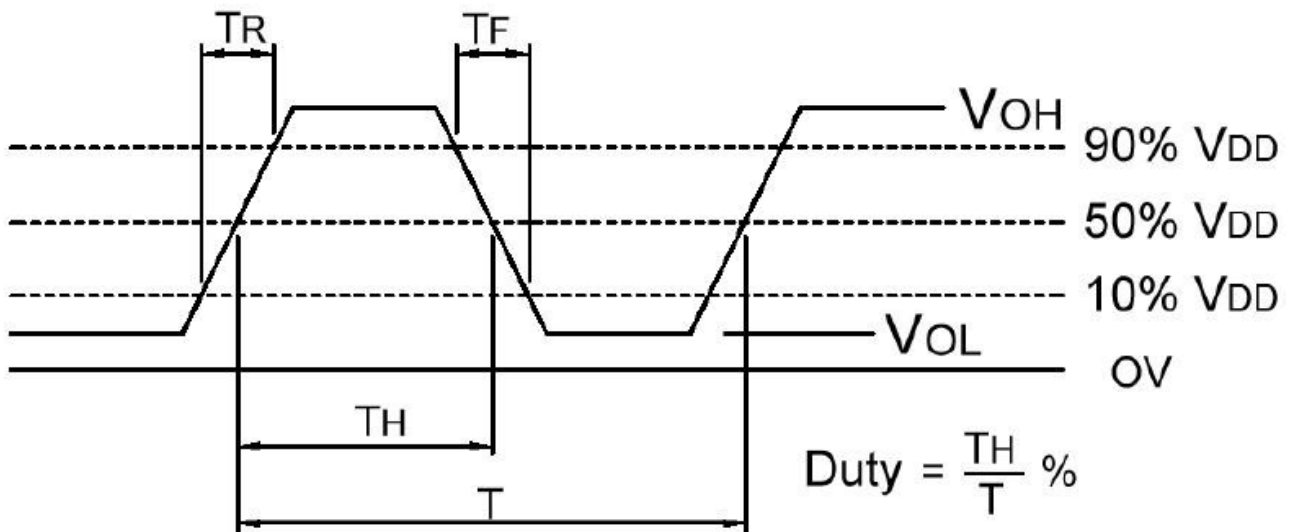
**Note1:** Tolerance  $\pm 0.2$ mm without mark



### 3、 Test Circuit (CMOS LOAD)



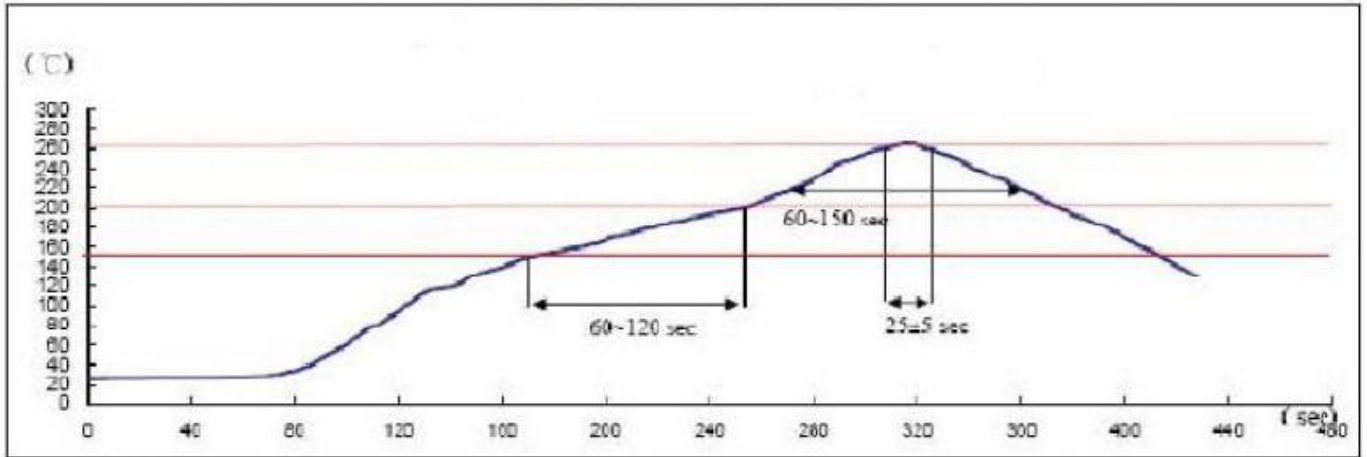
### 4、 Output Waveform(CMOS LOAD)





## 5、RECOMMENDED IR REFLOW PROFILE

### ➤ IR REFLOW PROFILE OF CERAMIC SMD PRODUCTS FOR Pb FREE PROCESS



IR-Reflow Test

Reference Standard : JEDEC-STD 020

Test Conditions: Pre-heating : 150°C to 200 °C, 60~120 sec

Heating : 217 °C , 60~150 sec

Peak Temperature : 260±5 °C, 25±5 sec

## 6、Package: Tape & Reel (mm)

